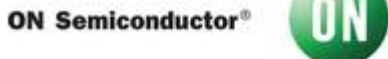



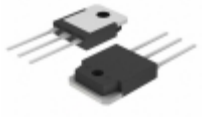
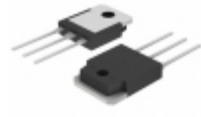



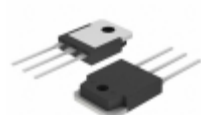


|   |   |
|---|---|
|  | <h2 style="color: red;">FQA28N50</h2>   |
|   | <p><b>Hersteller-Teilenummer:</b> FQA28N50</p> <hr/> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 500V 28.4A TO-3P</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">FQA28N50.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 15906 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | FQA28N50  |
| Hersteller                                       | AMI Semiconductor / ON Semiconductor  |
| Beschreibung                                     | MOSFET N-CH 500V 28.4A TO-3P  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> , |
| Teilstatus                                       | 15906 pcs Stock   |
| detaillierte Beschreibung                        | N-Channel 500V 28.4A (Tc) 310W (Tc) Through Hole                                  |
| Serie  | QFET®   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)  |
| Befestigungsart                                  | Through Hole  |
| Verpackung / Gehäuse                             | TO-3P-3, SC-65-3  |
| Supplier Device-Gehäuse                          | TO-3PN  |
| Verlustleistung (max)                            | 310W (Tc)   |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 500V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 28.4A (Tc)  |
| Rds On (Max) @ Id, Vgs                           | 160 mOhm @ 14.2A, 10V   |
| VGS (th) (Max) @ Id                              | 5V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 140nC @ 10V   |
| Eingabekapazität (Ciss) (Max) @ Vds              | 5600pF @ 25V  |
| Antriebsspannung (Max Rds On, Min Rds On)        | 10V   |
| Vgs (Max)  | ±30V  |
| Verpackung                                       | Tube  |
| Bleifreier Status / RoHS-Status                  | Lead free / RoHS Compliant  |
| Feuchtigkeitsempfindlichkeitsniveau (MSL)        | 1 (Unlimited)   |



















































FQA28N50 ist neu im Original, Suche FQA28N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA28N50 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA28N50: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |  |  |
|---|--|--|--|
| <br><b>FQA28N15_F109</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 150V 33A TO-3P | <br><b>FQA28N50_F109</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 500V 28.4A TO-3PN | <br><b>FQA28N15</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 150V 33A TO-3P              | <br><b>FQA30N40</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 400V 30A TO-3P         |
| <br><b>FQA28N50F</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 500V 28.4A TO-3P             | <br><b>FQA28N50</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 500V 28.4A TO-3P                 | <br><b>FQA28N50F</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 500V 28.4A TO-3P | <br><b>FQA28N50_F109</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 500V 28.4A TO-3PN |

### heiße Teile

Mehr

|   |   |   |   |   |
|---|---|---|---|---|
|  FQA18N40  |  FQA18N50      |  FQA19N20C     |  FQA19N20C     |  FQA19N20L     |
|  FQA19N20L |  FQA19N60      |  FQA19N60      |  FQA20N40      |  FQA20N40      |
|  FQA20N50  |  FQA20N60      |  FQA20N80      |  FQA24N50      |  FQA24N50      |
|  FQA24N50F |  FQA24N50F     |  FQA24N60      |  FQA24N60      |  FQA27N25      |
|  FQA27N25  |  FQA28N15      |  FQA28N15      |  FQA28N15_F109 |  FQA28N15_F109 |
|  FQA28N50  |  FQA28N50F     |  FQA28N50F     |  FQA30N40      |  FQA30N40      |
|  FQA32N20C |  FQA32N20C     |  FQA33N10      |  FQA33N10      |  FQA33N10L     |
|  FQA33N10L |  FQA34N20      |  FQA34N20      |  FQA34N20L     |  FQA34N20L     |
|  FQA34N25  |  FQA34N25      |  FQA35N40      |  FQA35N40      |  FQA36P15      |
|  FQA36P15  |  FQA36P15_F109 |  FQA36P15_F109 |  FQA38N30      |  FQA38N30      |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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